

SS32F-AT THRU SS320F-AT

SURFACE MOUNT SCHOTTKY BARRIER RECTIFIERS

Forward Current: 3.0A

Reverse Voltage: 20V to 200V

FEATURES

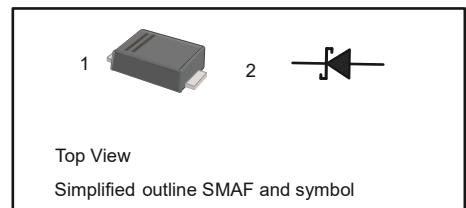
- ◆ For surface mount applications
- ◆ High forward surge current capability
- ◆ Low power loss, high efficiency
- ◆ Metal silicon junction, majority carriers conduction

MECHANICAL DATA

- ◆ Case: SMAF molded plastic body
- ◆ Terminals: Solderable per MIL-STD-750 , Method 2026
- ◆ Weight: Approximated 0.027 grams

PINNING

| PIN | DESCRIPTION |
|-----|-------------|
| 1 | Cathode |
| 2 | Anode |



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase half-wave 60 Hz, resistive or inductive load, for capacitive load current derating by 20 %.

| PARAMETER | SYMBOL | SS32F-AT | SS34F-AT | SS34AF-AT | SS36F-AT | SS38F-AT | SS310F-AT | SS312F-AT | SS315F-AT | SS320F-AT | UNIT |
|--|--------------------|----------|----------|-----------|----------|-------------|-----------|-----------|-----------|-----------|------|
| Maximum Repetitive Peak Reverse Voltage | V _{RRM} | 20 | 40 | 45 | 60 | 80 | 100 | 120 | 150 | 200 | V |
| Maximum RMS Voltage | V _{RMS} | 14 | 28 | 31.5 | 42 | 56 | 70 | 84 | 105 | 140 | V |
| Maximum DC Blocking Voltage | V _{DC} | 20 | 40 | 45 | 60 | 80 | 100 | 120 | 150 | 200 | V |
| Maximum Average Forward Rectified Current | I _{F(AV)} | | | | | | 3.0 | | | | A |
| Peak Forward Surge Current (Note1) | I _{FSM} | | | | | | 80 | | | | A |
| Maximum Forward Voltage at 3.0 A | V _F | 0.55 | | 0.70 | | | 0.85 | | 0.95 | | V |
| Maximum DC Reverse Current at Rated DC Blocking Voltage at T _A =25°C at T _A =100°C | I _R | | 0.5 | | 5 | | | 0.3 | | 3 | mA |
| Typical Junction Capacitance (Note2) | C _J | | 250 | | | | | 180 | | | pF |
| Typical Thermal Resistance (Note3) | R _{θJA} | | | | | 70 | | | | | °C/W |
| Operating Temperature Range | T _J | | | | | -55 to +125 | | | | | °C |
| Storage Temperature Range | T _{STG} | | | | | -55 to +150 | | | | | °C |

Notes: 1. Measured at 8.3 ms single half sine wave superimposed on rated load (JEDEC Method).

2. Measured at 1MHz and applied reverse voltage of 4 V D C.

3. P.C.B. mounted with 2.0" X 2.0" (5 X 5 cm) copper pad areas.

Dated: 05/2017
Rev:2.0

SS32F-AT THRU SS320F-AT

RATINGS AND CHARACTERISTIC CURVES

Fig.1 Forward Current Derating Curve

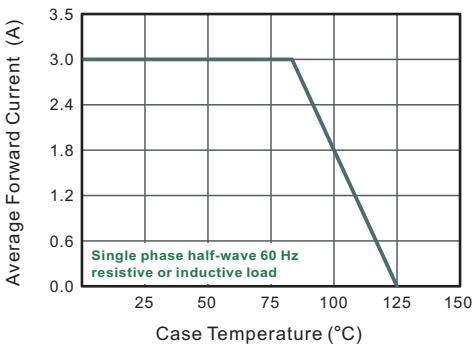
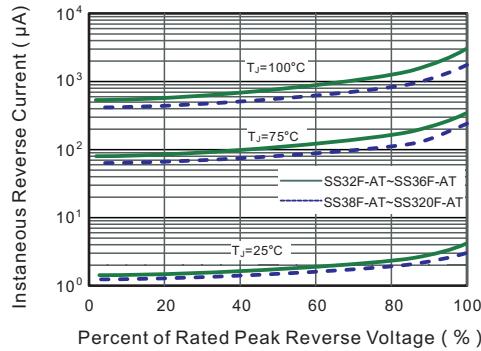


Fig.2 Typical Reverse Characteristics



SS36F

Fig.3 Typical Forward Characteristic

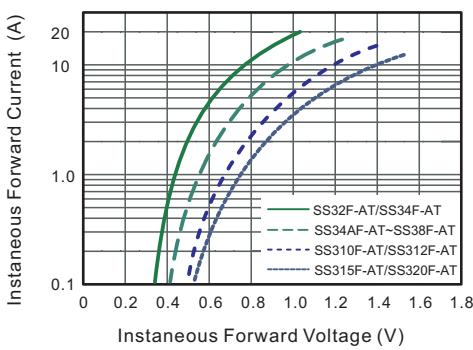


Fig.4 Typical Junction Capacitance

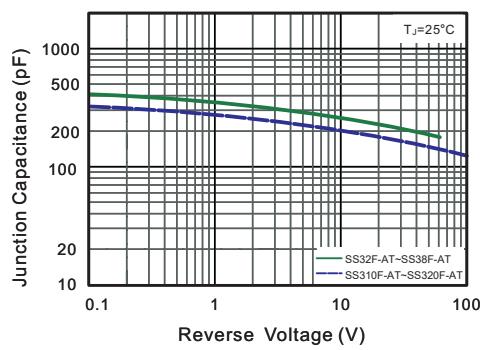


Fig.5 Maximum Non-Repetitive Peak Forward Surge Current

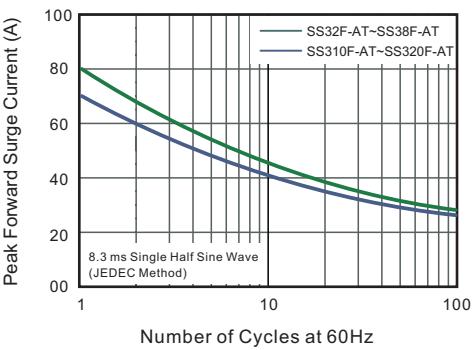
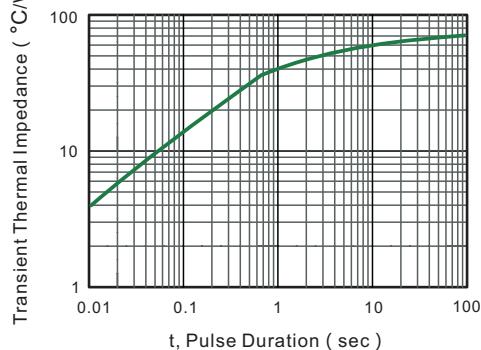


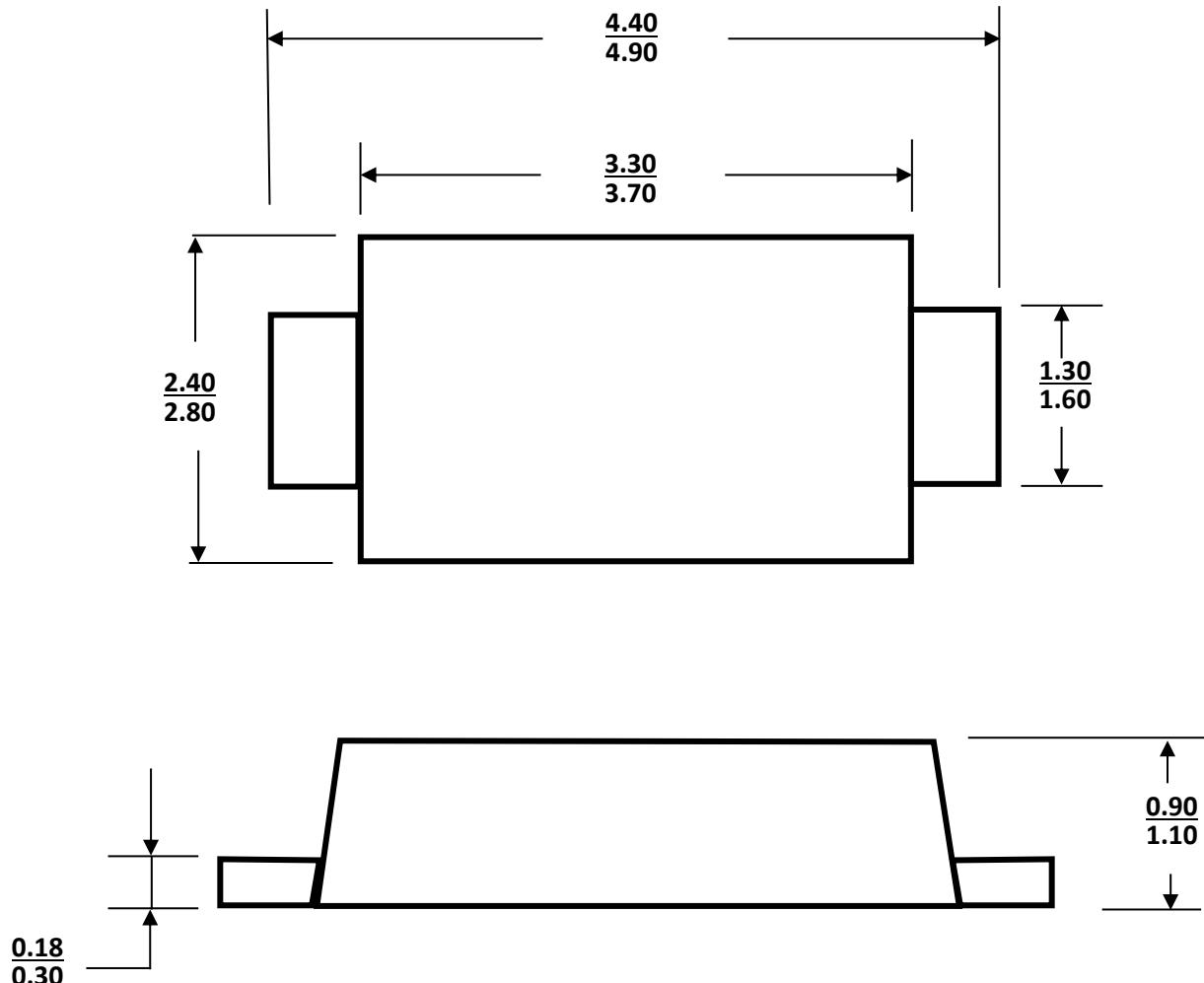
Fig.5-Typical Transient Thermal Impedance



SS32F-AT THRU SS320F-AT

PACKAGE OUTLINE

SMAF



Dimensions in millimeters

ORDERING INFORMATION

| Device | Package | Shipping |
|-------------------------|---------|---------------------------------|
| SS32F-AT thru SS320F-AT | SMAF | 3,000/Tape & Reel (7 inches) |
| | | 10,000/ Tape & Reel (13 inches) |

Dated: 05/2017
Rev:2.0